

GET A QUOTE

895 nm Laser Diode | PH895DBR Series

PH895DBR Series High-Power Single-Frequency Laser Diode 895 nm Laser Diode

Technology

- DBR Single-Frequency Laser Chip
- AlGaAs QW Active Layer
- Epi designed for high reliability

Features

- Available in several package styles
- Pulsed operation for spectral stability at short pulse lengths
- High power for CW applications
- High Slope Efficiency

Description

The PH895DBR Series of high-power edge-emitting lasers are based on Photodigm's advanced single-frequency laser technology. It provides a diffraction limited, single lateral and longitudinal mode beam.

Facets are passivated for high-power reliability. **895 nm laser diodes** are used in atomic spectroscopy for cesium based applications. It is certified to be resonant with the Cs D1 line.

Absolute Maximum Rating

Parameter	Symbol	Unit	Min	Max
Storage Temperature	T_{STG}	°C	0	80
Operating Temperature	T _{OP}	°C	5.0	70
CW Laser Forward Current, T=T _{op}	l _F	mA	-	200**
Pulsed Laser Forward Current, T=25°C,	l _E	А		O.F.
PW=300 ns, DC=10%	IF.	A	-	0.5
Laser Reverse Voltage	V _R	V	-	0.0
Photodiode Forward Current 1/2/	l _P	mA	-	5.0
Photodiode Reverse Voltage 1/2/	V_R	V	-	20.0

Photodiode Dark Current, V _R =10V, LD I _F =0, 1/2/	I _D	nA	-	50
TEC Current 1/2/	I _{TEC}	А	-2.5	2.5
TEC Voltage 1/2/	V _{TEC}	V	-6.0	6.0
Thermistor Current 1/2/	I _{THRM}	mA	-	1.0
Thermistor Voltage 1/2/	V _{THRM}	V	-	10
ESD (HBM)	-	V	-	500
External Back Reflection	-	dB	-	-14
Lead Soldering Temperature, 10 sec. Max., 1/2/	-	°C	-	260
Fiber Pull Force <u>1</u> /	-	Ν	-	5.0
Fiber Bend Radius <u>1</u> /	-	mm	-	35

<u>1</u>/ Butterfly package <u>2</u>/ TO8 package**Do not exceed drive current or operating power of supplied LIV

CW Characteristics at $T_C = 25$ °C unless otherwise specified

Parameter	Symbol	Unit	Min	Тур	Max
Center Wavelength	$\lambda_{\scriptscriptstyle C}$	nm	893	895	897
Optical Output Power @ LIV current	Po	mW	See Power Options Call- out		
Slope Efficiency, <u>1</u> /	η _d	W/A	0.3	0.36	
Slope Efficiency	$\eta_{ ext{d}}$	W/A	0.6	0.72	-
Threshold Current	I _{th}	mA	-	40	50
Laser Series Resistance	Rs	Ω	-	2.5	3.5
Laser Forward Voltage	VF	V	-	2.0	2.5
Thermistor Resistance @ 25°C, <u>1</u> / <u>2</u> /	R _T	ΚΩ	-	10	-
Photodiode Dark Current, V_R =10V, LD I_F =0, $\underline{1}/\underline{2}/$	I _D	nA	-	-	50
Laser Line Width	Δν	MHz	-	0.5	1.0
Beam Divergence @ FWHM	θп×θ⊥	0	-	6 X 32	8 X 34
Beam Divergence @ FWHM	θи×θ⊥	0	-	6 X 32	8 X 34

Side Mode Suppression Ratio	SMSR	dB	-30	-	-
Polarization Extinction Ratio, <u>1</u> /	PER	dB	-16	-19	-
Laser Polarization				TE	
Mode Structure			Fundamental Mode		

<u>1</u>/ Butterfly package <u>2</u>/ TO-8 package

Handling Precautions

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.

How To Order

Part number example: PH895DBR080CM. Assign optical power from those shown below. Use a

three-digit format for all power entries. Call factory for special performance selection and certification to certain atomic absorption lines. Butterfly package is offered only at 50% of output powers shown, and is not recommended for spectroscopy applications. See Photodigm's application note titled "Optical Feedback"

Package Type

(CS) Chip on Submount

(CM) 'C' Mount

(T8) TO-8

(BF) Butterfly

Minimum Power (mW)

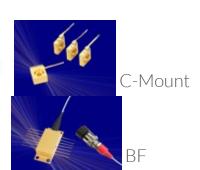
040 180

080 240

120 280



Chip on Submount (CS)





- 0



Blog Careers FAQ Literature News Tradeshows

1155 E. Collins Blvd., Suite 200 Richardson TX 75081 972-235-7584

© 2019 Photodigm, Inc.